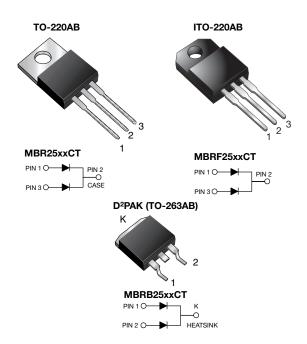
## MBR25xxCT, MBRF25xxCT, MBRB25xxCT

Vishay General Semiconductor

RoHS

# **Dual Common Cathode Schottky Rectifier**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 12.5 A			
$V_{RRM}$	35 V, 45 V			
I <sub>FSM</sub>	150 A			
$V_{F}$	0.73 V at 30 A			
T <sub>J</sub> max.	150 °C			
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	Common cathode			

#### **FEATURES**

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3\_A
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB) Epoxy meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B, ...)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless of	therwise noted)				_
PARAMETER		SYMBOL	MBR2535CT	MBR2545CT	UNIT
Maximum repetitive peak reverse voltage		$V_{RRM}$	35	45	
Working peak reverse voltage		$V_{RWM}$	35	45	V
Maximum DC blocking voltage		$V_{DC}$	35	45	
Maximum average forward rectified current at $T_C = 130$ °C	total device		25		A
	per diode	I <sub>F(AV)</sub>	12.5		
Peak forward surge current 8.3 ms single half sine-wave rated load per diode	I <sub>FSM</sub>	150		- A	
Peak repetitive reverse surge current per diode at $t_p = 2 \mu s$ , 1 kHz		I <sub>RRM</sub>	1.0		
Peak non-repetitive reverse energy (8/20 μs waveform) per diode		E <sub>RSM</sub>	2	25	mJ
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k $\Omega$			25		kV
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10	000	V/µs
Operating junction temperature range		TJ	-65 to	+150	°C
Storage temperature range		T <sub>STG</sub>	-65 to +175		]
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		$V_{AC}$	15	500	V



# MBR25xxCT, MBRF25xxCT, MBRB25xxCT

# Vishay General Semiconductor

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	MBR2535CT	MBR2545CT	UNIT	
Maximum instantaneous forward voltage per diode	I <sub>F</sub> = 15 A	T <sub>C</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	-			
		T <sub>C</sub> = 125 °C		-		v	
	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25 °C		0.82		V	
		T <sub>C</sub> = 125 °C		0.	73		
Maximum instantaneous reverse current at blocking voltage per diode		T <sub>C</sub> = 25 °C	I <sub>R</sub> <sup>(1)</sup>	0.2		mA	
	e per diode		'R`'	4	0	] "'A	

#### Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR2545CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR2545CT-E3/4W	1.85	4W	50/tube	Tube		
TO-220AB	MBR2545CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF2545CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB2545CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		
TO-263AB	MBRB2545CTHE3_A/P (1)	1.35	Р	50/tube	Tube		
TO-263AB	MBRB2545CTHE3_A/I (1)	1.35	I	800/reel	Tape and reel		

#### Note

(1) AEC-Q101 qualified

# Vishay General Semiconductor

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

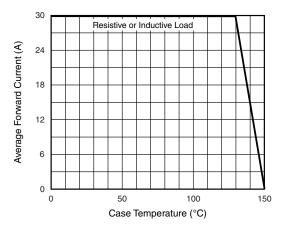


Fig. 1 - Forward Current Derating Curve

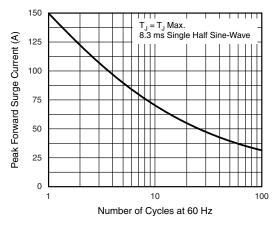


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

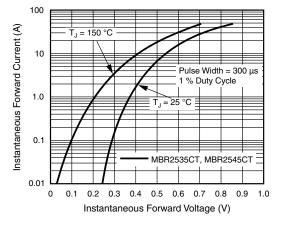


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

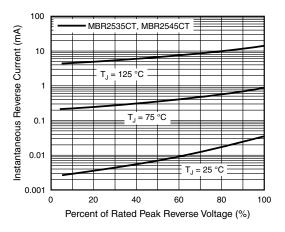


Fig. 4 - Typical Reverse Characteristics Per Diode

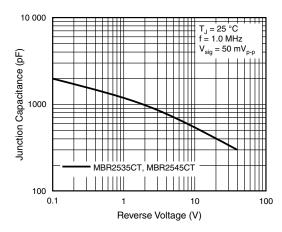


Fig. 5 - Typical Junction Capacitance Per Diode

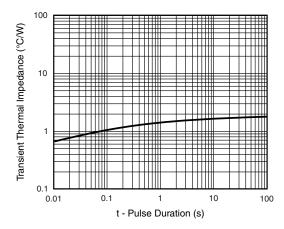


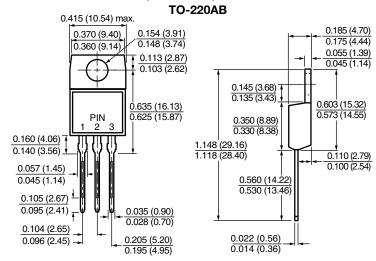
Fig. 6 - Typical Transient Thermal Impedance Per Diode

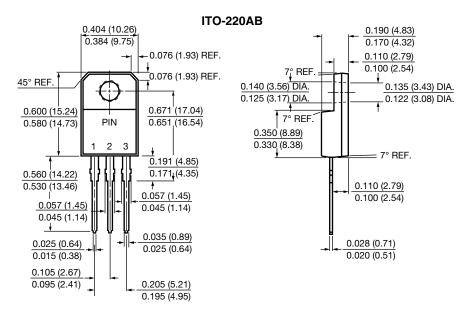




Vishay General Semiconductor

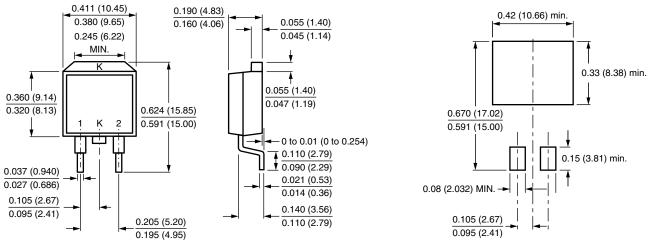
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





### D<sup>2</sup>PAK (TO-263AB)

## Mounting Pad Layout





## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.